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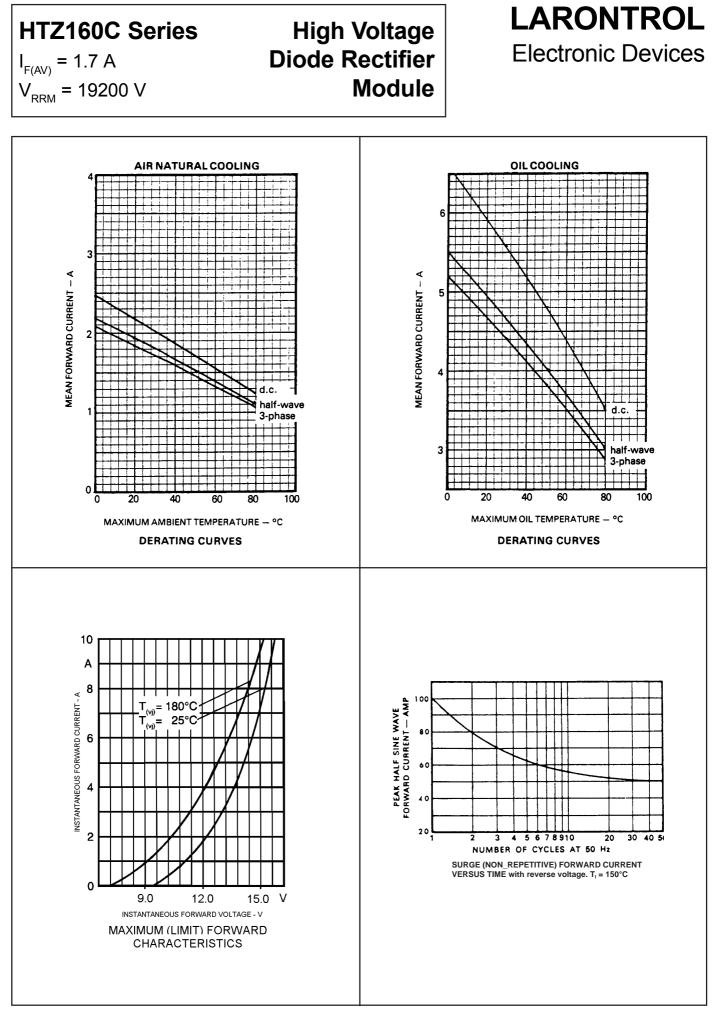
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HTZ160C Series I <sub>F(AV)</sub> = 1.7 A V <sub>RRM</sub> = 19200 V		•	High Voltage Diode Rectifier Module		LARONTROL Electronic Devices		
Type Number	Repetitiv Peak	e Minimum Avalanche Voltage V <sub>(BR)R</sub>					
HTZ160C19K19200HTZ160C17K16800HTZ160C14K14400HTZ160C12K12000		20400 18000 15600 13200		04 0 10			
CIRCUIT DI	AGRAM	V <sub>RRM</sub> 					
$\begin{array}{ll} \textbf{CURRENT RATINGS - AIR COOLED} \\ \textbf{I}_{F(AV)} & Mean forward current \\ \textbf{I}_{F} & Continuous (direct) forward current \\ \textbf{R}_{th(j-a)} & Thermal resistance junction to ambient \end{array}$			Half wave resistive load $T_{amb} = 35^{\circ}C$ $T_{amb} = 35^{\circ}C$		1.7 1.9 6.5	A A °C/W	
$\begin{array}{llllllllllllllllllllllllllllllllllll$		rrent ct) forward current	Half wave resistive load $T_{oil} = 60^{\circ}C$ $T_{oil} = 60^{\circ}C$		3.7 4.4 2.0	A A °C/W	
SURGE RATINGSI²tI²t for fusingIFSMSurge (non-repetitive) forward current		10 ms half sine T <sub>vj</sub> = 150°C T <sub>vj</sub> = 150°C		50 100	A²sec A		
TEMPERATURE AND FREQUENCY RATINGST_vjVirtual junction temperatureT_stgStorage temperature rangefFrequency range		emperature ture range	Forward (conducting) Reverse (blocking)		180 180 -40 to 100 20 to 400	°C °C ℃ Hz	
CHARACTERISTICS $T_{case} = 25^{\circ}C$ unless otherwise $V_{FM}$ Forward voltage $I_{RM}$ Peak reverse current		se stated At 2 Amps peak At V <sub>RRM</sub> ; T <sub>case</sub> = 150°C		max 12.0 max 0.5	V mA		
	ned Outlines shown are maximum in o.: 0,26 Kg	mm	115 90 45 45 45 45 TA MOUNTING BUS TAPPED M5, 2 0				
XYS reserves the right to change limits, test conditions and dimensions.					Issue 1 June 1998		

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